

붕소가 도핑된 다이아몬드 전극을 이용한 생체화학물질의 검출

이은주, *藤嶋 昭, 박수길
 충북대학교 공업화학과, *일본 동경대학 응용화학부

Detection of Bio-chemical by Boron-doped Diamond Electrode

Eun-ju Lee, A. Fujishima*, Soo-Gil Park
 Dept. of Industrial and Chemical Engineering, Chungbuk Nat'l University, Korea
 Dept. of Applied Chemistry Faculty of Eng., Tokyo Univ., Japan

Abstract - Selective, highly stable determination of serotonin was achieved in cyclic voltammetric measurement carried out at electrochemically treated conductive boron-doped diamond electrode. Boron-doped diamond electrodes were prepared on single crystal Si wafers by microwave plasma chemical vapor deposition and B_2O_3 was dissolved in acetone/methanol(9:1) mixture solution so that the B/C weight ratio ca. 10^4 ppm. Serotonin is a kind of indoleamines, which secreted from adrenal marrow cells. The serious problem to detection of serotonin is the interference phenomena of electroactive constituent, including AA.

In this study, electrochemical treatment of BDD was carried out to discriminate between serotonin and AA responses. Experimental results showed that the peak potential of AA oxidation shift to the positive direction and the oxidation peak of serotonin was unchanged.

1. Introduction

Polycrystalline chemical vapor-deposited(CVD) diamond films that are highly boron are metallic conductors. Boron-doped diamond exhibits several superior electrochemical properties that are significantly different from those of other carbon allotropes, e.g., glassy carbon(GC), pyrolytic graphite(PG), and highly oriented pyrolytic graphite(HOPG), which have been widely used as electrode materials for many years. BDD has received attention from electrochemists only in the past few years and no reports are published in our country. Its attractive features include a wide electrochemical potential window in aqueous media, very low capacitance, and extreme electrochemical stability. In addition, diamond electrodes have recently been found to show high resistance to deactivation, via fouling, and insensitivity to dissolved oxygen. These properties make diamond a promising material for electroanalytical applications. GC and HOPG are composed almost exclusively depend on several factors, including surface preparation, microstructure, and the presence of carbon-oxygen functional groups.

Serotonin, which is a component of neural transmission medium, takes effect on the transmission of nerve impulse. Many life phenomena are related to the concentration of serotonin in blood. Medically, serotonin has been used as a common emergency healthcare medicine. Therefore, the detection and determination of serotonin has attracted much

attention of the scientist in life science and medicine. Previous techniques for the determination of serotonin have been primarily based upon cation exchange, HPLC, CE, FIA, fluorimetry and sensors. However, the previous techniques suffered either tedious process or low sensitivity. A convenient method for direct determination of serotonin is strongly desired. In detecting serotonin, a serious source of interference is the presence of electroactive constituent, including ascorbic acid at a typical concentration of 10^{-4} M. For the most unmodified electrode materials, the voltammetric responses for these two species overlap, necessitating the use of electrode modification for selective serotonin measurements.

In this work, we have found that it is possible to achieve high selectivity for serotonin in the presence of ascorbic acid solution after a simple electrochemical pretreatment of the diamond electrode.

2. Experimental

2.1 Synthesis of conducting diamond films.

The boron-doped diamond thin films were grown on n-Si(100) substrate, which had been polished by 0.5 μ m diamond powder (Type Micron+SND, De Beers). Microwave plasma chemical vapor deposition (CVD) method was adopted by using commercial microwave plasma reactor(ASTeX Corp., Woburn, MA, USA). A 9:1 (v/v) mixture of acetone (Guaranteed, Koso Chemical Co.,Ltd.) and methanol(Guaranteed, Nacalai Tesque) (volume ratio) was used as the carbon source. B_2O_3 (Extra pure, Wako Chemical Co., Ltd) was used as the boron source. We dissolved B_2O_3 in this mixture solution so that the B/C weight ratio was ca. 10^2 ppm. 99.99% H_2 gas was used as the carrier gas, which carries carbon source into chamber. The H_2 flow rate was controlled at 532sccm(standard cubic centimeters per minute) and the carbon source flow rate was 10sccm with a mass flow controller. The total pressure was fixed 100 Torr. Diamond film deposition was carried out using a microwave power of 4000W. Raman spectroscopy was carried out using an Ar⁺ laser (wave length = 514.5nm) in a Renishaw Raman imaging microscope system (Renishaw System 2000): Surface morphology was observed by laser microscope (KEYENCE Co., Ltd., Model no. VF-7510), which magnification was 2500.

2.2 Electrochemical measurements.

L(-)-serotonin(AROS), L(+)-ascorbic acid and concd phosphate buffer (Aldrich), were used as received. All

other reagents were analytical reagent grade. All solutions were prepared in milli-Q water (Millipore).

The electrochemical measurements were carried out in a single compartment, three-electrode cell. SCE was used as the reference electrode, and Pt was used as the count electrode. All of the electrochemical measurements were taken using a WBCS 3000 measurement system (Wonatech Co.) and X-Y plotter. For the type of electrochemical pretreatment that was used for most of the measurement, the diamond electrodes were immersed in 0.1M Phosphate buffer, and a potential of +2.6V vs. SCE was supplied for 75min. Using a more stringent electrochemical pretreatment, the diamond electrodes were subjected to three potential sweeps at 0.1V/s between +4 and -4V vs SCE, and then the potential was held for 1 min at +4V in 0.1M Phosphate buffer solution.

3. Results and discussion

Fig. 1 is the microscope images of boron-doped diamond film, which deposited for 10hrs. The microwave-deposited polycrystalline boron-doped films were continuous and well faced, *i.e.*, only planar were observed. The Raman spectra of the 10²ppm doped films exhibited a sharp peak at 1334cm⁻¹ with a full width at half maximum of 7cm⁻¹, which is consistent with the literature. These results indicate that this film is of high quality. The resistivity of boron-doped diamond film was approximately 250Ωcm.

The shape of the voltammograms for serotonin oxidation, obtained at both as-grown (untreated) diamond electrode and after treatment are typical of an electrochemically irreversible process (Fig. 3A). The oxidation process for AA is even more electrochemically irreversible (Fig. 3B).



Fig.1 Scanning electron micrograph of the semiconducting boron-doped diamond thin film.

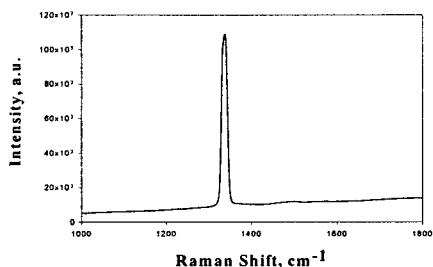
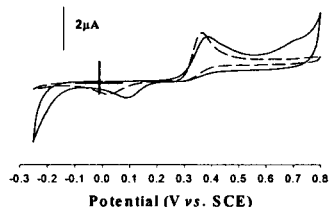


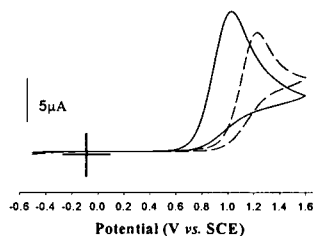
Fig. 2. Raman spectrum of the semiconducting boron-doped diamond thin film.

For serotonin oxidation on as-deposited diamond electrodes, the anodic peak ($E_{p,a}$) was $+0.4 \pm 0.01V$ vs. SCE, with a shift of only $70 \pm 10mV$ after treatment. For ascorbic acid oxidation at the untreated diamond electrode $E_{p,a}$ was $1.03 \pm 0.01V$ vs. SCE. After treatment, the $E_{p,a}$ value shifted to $1.23 \pm 0.01V$ vs. SCE.

The extreme difference in electrochemical behavior of serotonin and ascorbic acid as a result of the oxidation pretreatment is surprising. Two possible explanations are as follows. First, nondiamond carbon impurities (sp^2 carbon) can be electrochemically oxidized, either removing them or rendering them inactive, thereby suppressing their contribution to the electrochemical response. It was already reported that dioxygen reduction in acid solution at conductive diamond electrodes was suppressed by polarization at relatively positive potentials in alkaline electrolytes. In present case, oxidized diamond surface acquires surface dipoles as a result of introducing oxygen-containing functional groups, which then electrostatically repel both anions and neutral molecules with strong dipoles.



(A)



(B)

Fig. 3. Cyclic voltammograms for (A) 0.1mM serotonin and (B) 1mM ascorbic acid at untreated (solid lines) and electrochemically treated (dashed lines) diamond electrodes in 0.1M phosphate buffer solution. Sweep rate, 1mV

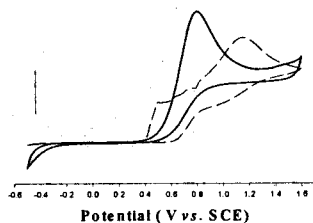


Fig. 4. Cyclic voltammograms for a 0.1M phosphate buffer solution containing 0.1mM serotonin and 1mM ascorbic acid at untreated (solid lines) and treated (dashed lines) diamond electrode. Sweep rate, 1mV/s.

Cyclic voltammograms obtained at a diamond thin film electrode for a solution containing both serotonin and ascorbic acid in 0.1M phosphate buffer solution are shown in Fig. 4. The curve obtained before treatment exhibited a single broad peak, while that for the treated diamond electrode exhibited two anodic peaks (serotonin at +0.42V and ascorbic acid 1.2V vs SCE). For the untreated electrode, the single broad peak can be attributed to serotonin oxidation, while the ascorbic acid oxidation peak is presumed to be absent due to the catalytic regeneration of serotonin, which is a well-known process occurring on unmodified carbon electrode. On the treated diamond electrode, due to the significant repulsive catalytic chemion of ascorbic acid, the contribution from catalytic reaction appears to be strongly suppressed.

4. Conclusion

In this work, we have showed that serotonin and ascorbic acid can be selectively determined in acidic media using an electrochemically pretreated diamond electrode. The unique features of the treated diamond electrode include very high sensitivity, remarkably good long-term stability, very good selectivity, insensitivity to oxygen, and ease of preparation. We are currently in the process of attempting to obtain more clear peak separation and detect very low concentration of serotonin.

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